

PHOTOCOUPLER PS2702-1

HIGH ISOLATION VOLTAGE DARLINGTON TRANSISTOR SOP MULTI PHOTOCOUPLER SERIES -NEPOC Series-

DESCRIPTION

The PS2702-1 is an optically coupled isolator containing a GaAs light emitting diode and an NPN silicon darlington-connected phototransistor.

This is mounted in a plastic SOP (Small Out-line Package) for high density applications.

This package has shield effect to cut off ambient light.

FEATURES

- High current transfer ratio (CTR = 2 000 % TYP.)
- High isolation voltage (BV = 3 750 Vr.m.s.)
- Small and thin (SOP) package
- High-speed switching (tr, tr = 200 μ s TYP.)
- Ordering number of taping product: PS2702-1-F3, F4
- UL approved: File No. E72422 (S)
- VDE0884 approved (Option)

APPLICATIONS

- Hybrid IC
- Telephone/FAX
- FA/OA equipment
- Programmable logic controllers

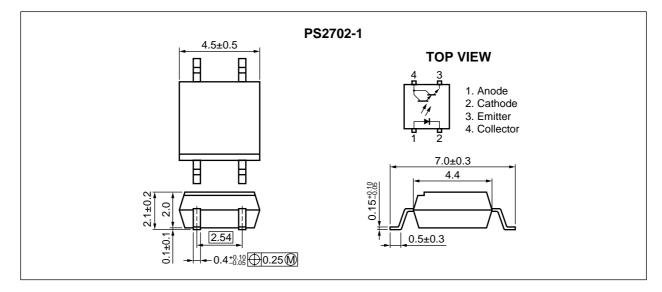
ORDERING INFORMATION

Part Number	Package	Safety Standard Approval
PS2702-1	4-pin SOP	Standard specification products
		UL approved
PS2702-1-V	4-pin SOP	VDE0884 specification products (Option)

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* PACKAGE DIMENSIONS (in millimeters)



Parameter		Symbol	Ratings	Unit
Diode	Forward Current (DC)	lf	50	mA
	Reverse Voltage	VR	6.0	V
	Power Dissipation Derating	⊿P _D /°C	0.8	mW/°C
	Power Dissipation	PD	80	mW
	Peak Forward Current ^{*1}	I FP	1	А
Transistor	Collector to Emitter Voltage	Vceo	40	V
	Emitter to Collector Voltage	Veco	6	V
	Collector Current	lc	200	mA
	Power Dissipation Derating	⊿Pc/°C	1.5	mW/°C
	Power Dissipation	Pc	150	mW
Isolation Voltage ^{*2}		BV	3 750	Vr.m.s.
Operating Ambient Temperature		TA	–55 to +100	°C
Storage Temperature		Tstg	-55 to +150	°C

ABSOLUTE MAXIMUM RATINGS (TA = 25 °C, unless otherwise specified)

*1 PW = 100 μ s, Duty Cycle = 1 %

*2 AC voltage for 1 minute at $T_A = 25$ °C, RH = 60 % between input and output

	Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Diode	Forward Voltage	VF	IF = 5 mA		1.1	1.4	V
	Reverse Current	IR	Vr = 5 V			5	μA
	Terminal Capacitance	Ct	V = 0 V, f = 1 MHz		30		pF
Transistor	Collector to Emitter Dark Current	ICEO	IF = 0 mA, VCE = 40 V			400	nA
Coupled Current Transfer Ratio (Ic/IF) ⁻¹ Collector Saturation Voltage Isolation Resistance Isolation Capacitance Rise Time ⁻²	CTR	IF = 1 mA, VcE = 2 V	200	2 000		%	
	VCE (sat)	IF = 1 mA, Ic = 2 mA			1.0	V	
	Isolation Resistance	Ri-o	VI-0 = 1 kVDC	10 ¹¹			Ω
	Isolation Capacitance	CI-O	V = 0 V, f = 1 MHz		0.4		pF
	Rise Time ^{⁺₂}	tr	$Vcc = 5 V$, $Ic = 2 mA$, $RL = 100 \Omega$		200		μs
	Fall Time ^{*2}	tŕ			200		

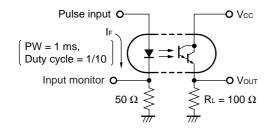
*1 CTR rank

K: 2 000 to (%)

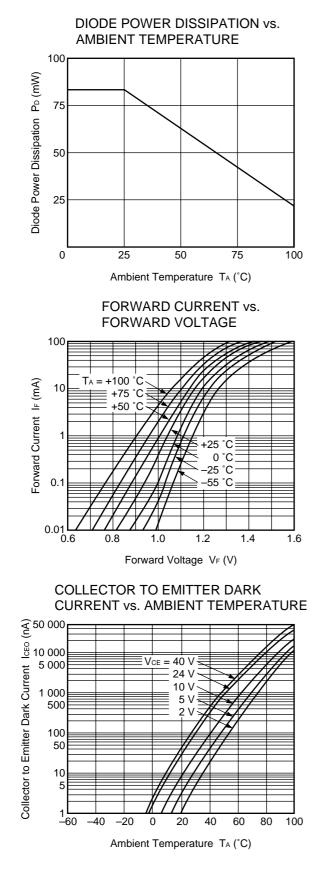
L: 700 to 3 400 (%)

M: 200 to 1 000 (%)

*2 Test circuit for switching time



* TYPICAL CHARACTERISTICS (TA = 25 °C, unless otherwise specified)

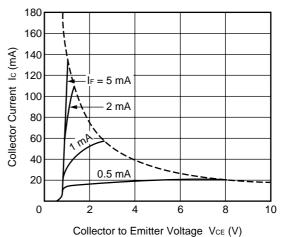


AMBIENT TEMPERATURE

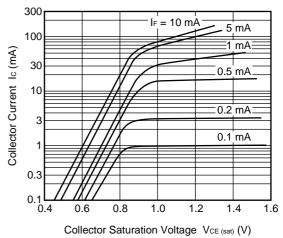
TRANSISTOR POWER DISSIPATION vs.

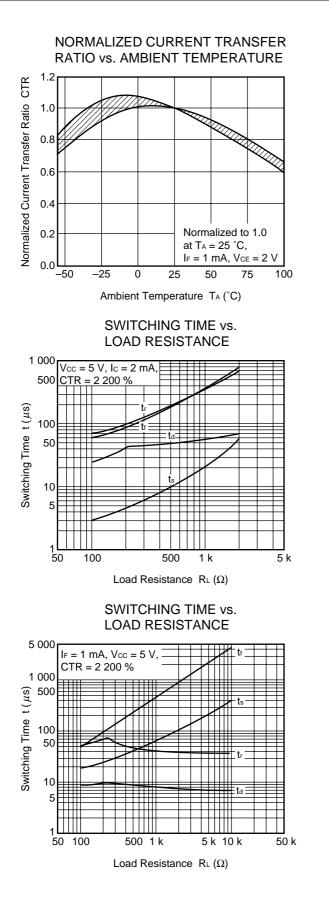
Ambient Temperature T_A (°C)

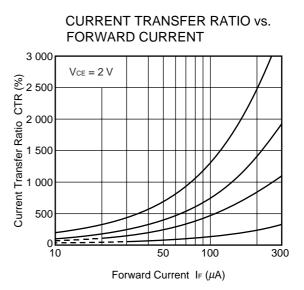
COLLECTOR CURRENT vs. COLLECTOR TO EMITTER VOLTAGE



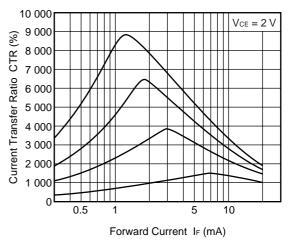
COLLECTOR CURRENT vs. COLLECTOR SATURATION VOLTAGE



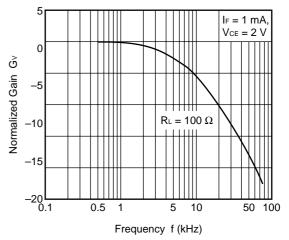


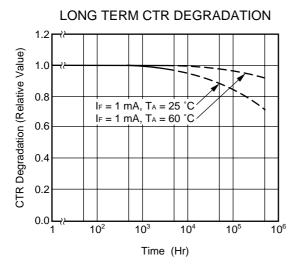


CURRENT TRANSFER RATIO vs. FORWARD CURRENT



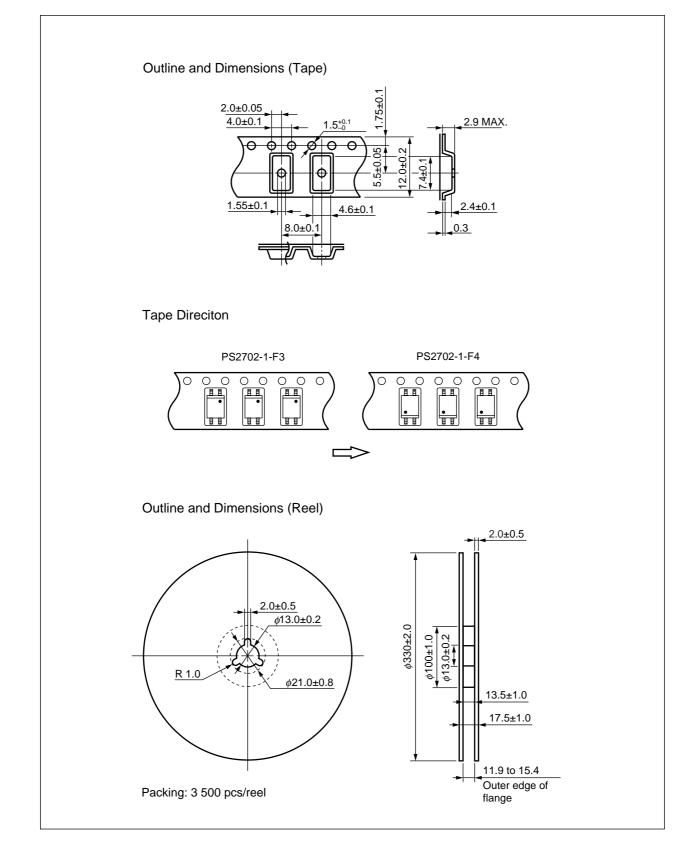
FREQUENCY RESPONSE





Remark The graphs indicate nominal characteristics.

* TAPING SPECIFICATIONS (in millimeters)



NOTES ON HANDLING

1. Recommended soldering conditions

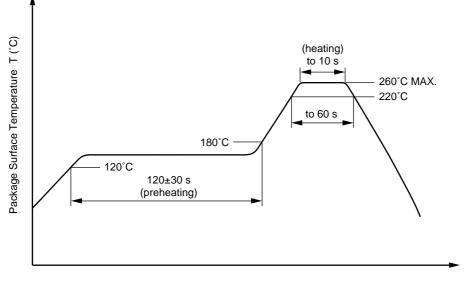
(1) Infrared reflow soldering

- · Peak reflow temperature
- Time of peak reflow temperature
- Time of temperature higher than 220°C
- Time to preheat temperature from 120 to 180°C
- Number of reflows
- Flux

260°C or below (package surface temperature) 10 seconds or less 60 seconds or less 120±30 s Three

Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt% is recommended.)

Recommended Temperature Profile of Infrared Reflow



Time (s)

(2) Wave soldering

- Temperature 260°C or below (molten solder temperature)
- Time 10 seconds or less
- 120°C or below (package surface temperature) · Preheating conditions
- Number of times One (Allowed to be dipped in solder including plastic mold portion.)
- Rosin flux containing small amount of chlorine (The flux with a maximum chlorine • Flux content of 0.2 Wt% is recommended.)

(3) Cautions

Fluxes

Avoid removing the residual flux with freon-based and chlorine-based cleaning solvent.

2. Cautions regarding noise

Be aware that when voltage is applied suddenly between the photocoupler's input and output or between collector-emitters at startup, the output side may enter the on state, even if the voltage is within the absolute maximum ratings.

★ USAGE CAUTIONS

- 1. Protect against static electricity when handling.
- 2. Avoid storage at a high temperature and high humidity.

★

SPECIFICATION OF VDE MARKS LICENSE DOCUMENT (VDE0884)

Parameter	Symbol	Speck	Unit
Application classification (DIN VDE 0109)			
for rated line voltages \leq 300 Vr.m.s.		IV	
for rated line voltages \leq 600 Vr.m.s.		III	
Climatic test class (DIN IEC 68 Teil 1/09.80)		55/100/21	
Dielectric strength			
maximum operating isolation voltage	UIORM	710	Vpeak
Test voltage (partial discharge test, procedure a for type test and random test)	Upr	850	Vpeak
$U_{\text{Pr}} = 1.2 \times U_{\text{IORM}}, \ P_{\text{d}} < 5 \ pC$			
Test voltage (partial discharge test, procedure b for all devices test)	Upr	1 140	Vpeak
$U_{pr} = 1.6 \times U_{IORM}, P_d < 5 pC$			
Highest permissible overvoltage	Utr	6 000	Vpeak
Degree of pollution (DIN VDE 0109)		2	
Clearance distance		> 5	mm
Creepage distance		> 5	mm
Comparative tracking index (DIN IEC 112/VDE 0303 part 1)	CTI	175	
Material group (DIN VDE 0109)		III a	
Storage temperature range	Tstg	-55 to +150	°C
Operating temperature range	TA	–55 to +100	°C
Isolation resistance, minimum value			
$V_{IO} = 500 \text{ V dc} \text{ at } T_A = 25 ^{\circ}\text{C}$	Ris MIN.	10 ¹²	Ω
$V_{IO} = 500 \text{ V} \text{ dc} \text{ at } T_A \text{ MAX. at least } 100 ^{\circ}\text{C}$	Ris MIN.	10 ¹¹	Ω
Safety maximum ratings (maximum permissible in case of fault, see thermal			
derating curve)			
Package temperature	Tsi	150	°C
Current (input current IF, Psi = 0)	Isi	200	mA
Power (output or total power dissipation)	Psi	300	mW
Isolation resistance			
Vio = 500 V dc at T _A = 175 °C (Tsi)	Ris MIN.	10 ⁹	Ω

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M8E 00.4-0110

SAFETY INFORMATION ON THIS PRODUCT

Caution GaAs Products	The product contains gallium arsenide, GaAs. GaAs vapor and powder are hazardous to human health if inhaled or ingested.
	Do not destroy or burn the product.
	Do not cut or cleave off any part of the product.
	Do not crush or chemically dissolve the product.
	Do not put the product in the mouth.
	Follow related laws and ordinances for disposal. The product should be excluded from general industrial waste or household garbage.

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